Growth of Mn_{4-x}Ga_xN epitaxial films and analysis of their magnetic structure by X-ray magnetic circular dichroism

1. Univ. of Tsukuba, 2. KEK

Aoi Hatate¹, T. Komori¹, T. Yasuda¹, T. Horiuchi¹, K. Amemiya², K. Toko¹, and T. Suemasu¹ E-mail: blueno.spin@gmail.com

[Introduction] We have focused on compensated ferrimagnetic $Mn_{4-x}Z_xN$ films (Z is a metal element), which are candidates for future domain wall motion (DWM) device materials. For instance, Mn_{4-x}Ni_xN has a magnetic compensation composition at RT^[1], which is confirmed by X-ray absorption spectroscopy (XAS) and X-ray magnetic circular dichroism (XMCD) measurements. Remarkably, in Mn_{3.85}Ni_{0.15}N, the DWM velocity reached 3,000 m/s at RT^[2] thanks to the angular momentum compensation. We expect that $Mn_{4-x}Ga_xN$ epitaxial films can be another candidate. R. Zhang *et al.* reported that bulk $Mn_{4-x}Ga_xN$ has a magnetic compensation composition^[3]. However, there have been no reports about the magnetic compensation of Mn_{4-x}Ga_xN films. This time, we report results about XAS and XMCD measurements on $Mn_{4-x}Ga_xN$ epitaxial films.

[Experiment] First we grew 23-nm-thick $Mn_{4-x}Ga_xN$ (x = 0.1 and 0.3) epitaxial films on SrTiO₃(001) substrates by molecular beam epitaxy. We performed XAS and XMCD measurements at the twin APPLE-II undulator beamline BL-16A of KEK-PF in Japan. The ±5 T magnetic field and circularly polarized X-rays were applied at the magic angle ($\theta \sim 55^{\circ}$). **[Result]** Figure 1 shows XAS and XMCD spectra on Mn- $L_{2,3}$ absorption edges in (a) Mn_{3.9}Ga_{0.1}N and (b) Mn_{3.7}Ga_{0.3}N at RT. XAS spectra seem to have no difference, suggesting that the valency number of Mn atoms was almost the same. In the XMCD spectra of Fig.1(a), the Mn- L_3 absorption edge contains negative α -peak and positive β -peak. According to K. Ito *et al.*^[4] Mn atoms at corner and face-centered sites mainly contribute to α and β peaks, respectively, in Mn₄N. In the XMCD spectra of Fig.1(b), the sign of β -peak is negative, although it is positive in Fig.1(a). It indicates that the direction of the magnetic moment of facecentered Mn reversed, and the magnetic moments of Mn atoms at both sites became parallel in Mn_{4-x}Ga_xN films with increasing the amount of Ga.

[Acknowledgment] The XAS and XMCD measurements were performed with the approval of the Photon Factory Program Advisory Committee (Proposal No. 2022G036).

[Reference]

- [1] T. Komori et al., J. Appl. Phys. 127, 043903 (2020).
- [2] S. Ghosh et al., Nano Lett. 21, 2580 (2021).
- [3] R. Zhang et al., Acta Mater, 234, 118021(2022).
- [4] K. Ito et al., Phys. Rev. B 101, 104401 (2020).

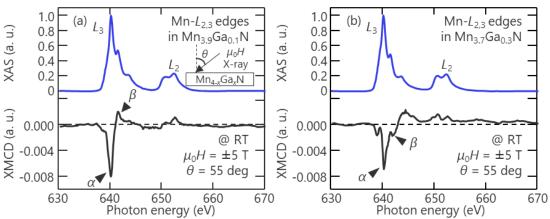


Fig. 1 XAS and XMCD spectra in (a) Mn_{3.9}Ga_{0.1}N and (b) Mn_{3.7}Ga_{0.3}N films at Mn-L_{2.3} edges